

Attorney's Docket No. 5308-156

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Ryu et al. Group Art Unit: 2811
Serial No.: 09/911,995 Confirmation No.: 5240
Filed: July 24, 2001 Examiner: Gene Munson
For: SILICON CARBIDE POWER METAL-OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS HAVING A SHORTING CHANNEL AND
METHODS OF FABRICATING SILICON CARBIDE METAL-OXIDE
SEMICONDUCTOR FIELD EFFECT TRANSISTORS HAVING A
SHORTING CHANNEL

Date: June 26, 2003

FAX RECEIVED

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Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

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TECHNOLOGY CENTER 2800

DUPLICATE INFORMATION DISCLOSURE STATEMENT

Sir:

Attached is a list of two documents on form PTO-1449. Copies of these documents have been previously provided to the Patent Office with previously submitted IDSs. It is requested that these documents be considered by the Examiner and officially made of record in accordance with the provisions of 37 C.F.R. § 1.97 and Section 609 of the M.P.E.P, as Applicants have complied with the requirements of this section. Applicants do not believe there is any fee associated with this submission, however, the Commissioner is hereby authorized to charge any additional fee, which may be required, or credit any refund, to our Deposit Account No. 50-0220.

Applicants note that the documents listed on the attached PTO-1449 form were previously submitted in two IDSs, however, the Examiner struck through the entries on both IDSs and indicated that no publication data was available. Applicants submit the present IDS responsive to a telephonic request from Examiner Munson and, request that the Examiner consider these references as prior art under 35 U.S.C. § 102(f) for purposes of examination of the present application. Applicants have attached a publication corresponding to item 2 on the form PTO-1449 as requested by Examiner Munson.

Accordingly, Applicants respectfully request that Examiner Munson consider the references on the 1449, initial the PTO-1449 and fax the initialed PTO 1449 to the

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undersigned attorney at (919) 854-1401. In view of the fact that the issue fee in the present case is due on July 7, 2003, Applicants respectfully request that Examiner Munson consider the references and return the initialed PTO-1449 before this date. Applicants appreciate Examiner Munson's assistance with this matter.

Respectfully submitted,



Elizabeth A. Stanek
Registration No. 48,568

Customer Number:

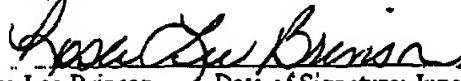


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PATENT TRADEMARK OFFICE

CERTIFICATE OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being sent by facsimile transmission to Box After Final, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, at (703) 872-9319 on June 26, 2003.


Rosa Lee Brinson Date of Signature: June 26, 2003

FORM PTO-1449 U.S. Department of Commerce Patent and Trademark Office LIST OF DOCUMENTS CITED BY APPLICANT (Use several sheets if necessary)			Attorney Docket Number 5308-156	Serial No. 09/911,995
Applicants: Ryu et al.				
			Filing Date: July 24, 2001	Group: 2811
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)				
	1	G.Y. Chung, C.C. Tin, J.R. Williams, K. McDonald, R.A. Weller, S.T. Pantelides, L.C. Feldman, M.K. Das, and J.W. Palmour, "Improved Inversion Channel Mobility for 4H-SiC MOSETs Following High Temperature Anneals in Nitric Oxide," <i>IEEE Electron Device Letters</i> accepted for publication, 2000 and published in Vol. 22, No. 4, April 2001.		
	2	Das, Mrinal K. Graduate thesis entitled, <i>Fundamental Studies of the Silicon Carbide MOS Structure</i> . Purdue University, December 1999.		

EXAMINER
 *EXAMINER

DATE CONSIDERED

Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.